## High Slew Rate, Wide Bandwidth, JFET Input Operational Amplifiers

These devices are a new generation of high speed JFET input monolithic operational amplifiers. Innovative design concepts along with JFET technology provide wide gain bandwidth product and high slew rate. Well-matched JFET input devices and advanced trim techniques ensure low input offset errors and bias currents. The all NPN output stage features large output voltage swing, no deadband crossover distortion, high capacitive drive capability, excellent phase and gain margins, low open loop output impedance, and symmetrical source/sink AC frequency response.

This series of devices is available in fully compensated or decompensated (AVCL $\leq 2$ ) and is specified over a commercial temperature range. They are pin compatible with existing Industry standard operational amplifiers, and allow the designer to easily upgrade the performance of existing designs.

- Wide Gain Bandwidth: 8.0 MHz for Fully Compensated Devices 16 MHz for Decompensated Devices
- High Slew Rate: $25 \mathrm{~V} / \mu \mathrm{s}$ for Fully Compensated Devices
$50 \mathrm{~V} / \mu \mathrm{s}$ for Decompensated Devices
- High Input Impedance: $10^{12} \Omega$
- Input Offset Voltage: 0.5 mV Maximum (Single Amplifier)
- Large Output Voltage Swing: -14.7 V to +14 V for

$$
\mathrm{V}_{\mathrm{CC}} / \mathrm{V}_{\mathrm{EE}}= \pm 15 \mathrm{~V}
$$

- Low Open Loop Output Impedance: $30 \Omega$ @ 1.0 MHz
- Low THD Distortion: 0.01\%
- Excellent Phase/Gain Margins: 55/7.6 dB for Fully Compensated Devices

ORDERING INFORMATION

| Op Amp Function | Fully Compensated | Avcl $\geq 2$ <br> Compensated | Operating Temperature Range | Package |
| :---: | :---: | :---: | :---: | :---: |
| Single | MC34081BD | MC34080BD | $\mathrm{T}_{\mathrm{A}}=0^{\circ}$ to $+70^{\circ} \mathrm{C}$ | SO-8 |
|  | MC34081BP | MC34080BP |  | Plastic DIP |
| Dual | MC34082P | MC34083BP |  | Plastic DIP |
| Quad | MC34084DW | MC34085BDW | $\mathrm{T}^{\prime} \mathrm{A}=0^{\circ}$ to $+70^{\circ} \mathrm{C}$ | SO-16L |
|  | MC34084P | MC34085BP |  | Plastic DIP |

PIN CONNECTIONS


## HIGH PERFORMANCE JFET INPUT OPERATIONAL AMPLIFIERS



PIN CONNECTIONS

(Single, Top View)


## MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
| :--- | :---: | :---: | :---: |
| Supply Voltage (from $\mathrm{V}_{\mathrm{CC}}$ to $\mathrm{V}_{\mathrm{EE}}$ ) | $\mathrm{V}_{\mathrm{S}}$ | +44 | V |
| Input Differential Voltage Range | $\mathrm{V}_{\text {IDR }}$ | (Note 1) | V |
| Input Voltage Range | $\mathrm{V}_{\text {IR }}$ | (Note 1) | V |
| Output Short Circuit Duration (Note 2) | tSC | Indefinite | sec |
| Operating Ambient Temperature Range | $\mathrm{T}_{\mathrm{A}}$ | 0 to +70 | ${ }^{\circ} \mathrm{C}$ |
| Operating Junction Temperature | $\mathrm{T}_{\mathrm{J}}$ | +125 | ${ }^{\circ} \mathrm{C}$ |
| Storage Temperature Range | $\mathrm{T}_{\text {stg }}$ | -65 to +165 | ${ }^{\circ} \mathrm{C}$ |

NOTES: 1. Either or both input voltages must not exceed the magnitude of $\mathrm{V}_{\mathrm{CC}}$ or $\mathrm{V}_{\mathrm{EE}}$.
2. Power dissipation must be considered to ensure maximum junction temperature $\left(T_{J}\right)$ is not exceeded.

Representative Schematic Diagram
(Each Amplifier)

*Pins 1 \& $5(\mathrm{MC} 34080,081)$ should not be directly grounded or connected to $\mathrm{V}_{\mathrm{CC}}$.

## MC34080 thru MC34085

DC ELECTRICAL CHARACTERISTICS $\left(\mathrm{V}_{\mathrm{CC}}=+15 \mathrm{~V}, \mathrm{~V}_{\mathrm{EE}}=-15 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=\mathrm{T}_{\text {low }}\right.$ to $\mathrm{T}_{\text {high }}$ [Note 3], unless otherwise noted. $)$

\begin{tabular}{|c|c|c|c|c|c|}
\hline Characteristics \& Symbol \& Min \& Typ \& Max \& Unit <br>
\hline ```
Input Offset Voltage (Note 4)
Single
$\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$
$\mathrm{T}_{\mathrm{A}}=0^{\circ}$ to $+70^{\circ} \mathrm{C}$ (MC34080B, MC34081B)
Dual
$\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$
$\mathrm{T}_{\mathrm{A}}=0^{\circ}$ to $+70^{\circ} \mathrm{C}$ (MC34082, MC34083)
Quad
$\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$
$\mathrm{T}_{\mathrm{A}}=0^{\circ}$ to $+70^{\circ} \mathrm{C}$ (MC34084, MC34085)

``` & \(\mathrm{V}_{1 \mathrm{O}}\) & \[
\begin{aligned}
& - \\
& - \\
& - \\
& -
\end{aligned}
\] & \[
\begin{aligned}
& 0.5 \\
& 1.0 \\
& - \\
& 6.0
\end{aligned}
\] & \[
\begin{aligned}
& 2.0 \\
& 4.0 \\
& 3.0 \\
& 5.0 \\
& 12 \\
& 14
\end{aligned}
\] & mV \\
\hline Average Temperature Coefficient of Offset Voltage & \(\Delta \mathrm{V}_{1 \mathrm{O}} / \Delta \mathrm{T}\) & - & 10 & - & \(\mu \mathrm{V} /{ }^{\circ} \mathrm{C}\) \\
\hline \[
\begin{aligned}
& \text { Input Bias Current (VCM = } 0 \text { Note 5) } \\
& T_{A}=+25^{\circ} \mathrm{C} \\
& T_{A}=0^{\circ} \text { to }+70^{\circ} \mathrm{C}
\end{aligned}
\] & IIB & - & 0.06 & \[
\begin{aligned}
& 0.2 \\
& 4.0
\end{aligned}
\] & nA \\
\hline \[
\begin{aligned}
& \text { Input Offset Current (VCM }=0 \text { Note 5) } \\
& \mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C} \\
& \mathrm{~T}_{\mathrm{A}}=0^{\circ} \text { to }+70^{\circ} \mathrm{C}
\end{aligned}
\] & 10 & - & & \[
\begin{aligned}
& 0.1 \\
& 2.0
\end{aligned}
\] & nA \\
\hline \[
\begin{aligned}
& \text { Large Signal Voltage Gain (VO } \left.= \pm 10 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=2.0 \mathrm{k}\right) \\
& \mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C} \\
& \mathrm{~T}_{\mathrm{A}}=\mathrm{T}_{\text {low }} \text { to } \mathrm{T}_{\text {high }}
\end{aligned}
\] & Avol & \[
\begin{aligned}
& 25 \\
& 15
\end{aligned}
\] & & & V/mV \\
\hline Output Voltage Swing
\[
\begin{aligned}
& \mathrm{R}_{\mathrm{L}}=2.0 \mathrm{k}, \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C} \\
& \mathrm{R}_{\mathrm{L}}=10 \mathrm{k}, \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C} \\
& \mathrm{R}_{\mathrm{L}}=10 \mathrm{k}, \mathrm{~T}_{\mathrm{A}}=\mathrm{T}_{\text {low }} \text { to } \mathrm{T}_{\text {high }} \\
& \mathrm{R}_{\mathrm{L}}=2.0 \mathrm{k}, \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C} \\
& \mathrm{R}_{\mathrm{L}}=10 \mathrm{k}, \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C} \\
& R_{\mathrm{L}}=10 \mathrm{k}, \mathrm{~T}_{\mathrm{A}}=\mathrm{T}_{\text {low }} \text { to } \mathrm{T}_{\text {high }}
\end{aligned}
\] & \(\mathrm{V}_{\mathrm{OH}}\)

\(\mathrm{V}_{\mathrm{OL}}\) & \[
\begin{aligned}
& 13.2 \\
& 13.4 \\
& 13.4
\end{aligned}
\] & \[
\begin{gathered}
13.7 \\
13.9 \\
- \\
\hline-14.1 \\
-14.7
\end{gathered}
\] & \[
\begin{gathered}
\text { - } \\
\hline-13.5 \\
-14.1 \\
-14.0
\end{gathered}
\] & V \\
\hline Output Short Circuit Current ( \(\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}\) ) Input Overdrive \(=1.0 \mathrm{~V}\), Output to Ground Source Sink & ISC & 20
20 & \[
\begin{aligned}
& 31 \\
& 28
\end{aligned}
\] & - & mA \\
\hline Input Common Mode Voltage Range
\[
\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}
\] & VICR & & \[
\begin{aligned}
& E E+4.0 \\
& C C-2
\end{aligned}
\] & & V \\
\hline Common Mode Rejection Ratio ( \(\mathrm{R}_{\mathrm{S}} \leq 10 \mathrm{k}, \mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}\) ) & CMRR & 70 & 90 & - & dB \\
\hline Power Supply Rejection Ratio (RS \(=100 \Omega, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}\) ) & PSRR & 70 & 86 & - & dB \\
\hline \begin{tabular}{l}
Power Supply Current \\
Single
\[
\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}
\] \\
\(\mathrm{T}_{\mathrm{A}}=\mathrm{T}_{\text {low }}\) to \(\mathrm{T}_{\text {high }}\) \\
Dual
\[
\begin{aligned}
& \mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C} \\
& \mathrm{~T}_{\mathrm{A}}=\mathrm{T}_{\text {low }} \text { to } \mathrm{T}_{\text {high }}
\end{aligned}
\] \\
Quad
\[
\begin{aligned}
& \mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C} \\
& \mathrm{~T}_{\mathrm{A}}=\mathrm{T}_{\text {low }} \text { to } \mathrm{T}_{\text {high }}
\end{aligned}
\]
\end{tabular} & ID & - & \[
\begin{aligned}
& 2.5 \\
& - \\
& 4.9 \\
& - \\
& 9.7
\end{aligned}
\] & \[
\begin{aligned}
& 3.4 \\
& 4.2 \\
& \\
& 6.0 \\
& 7.5 \\
& \\
& 11 \\
& 13
\end{aligned}
\] & mA \\
\hline
\end{tabular}

NOTES: (continued)
\begin{tabular}{rrr} 
3. \(T_{\text {low }}=0^{\circ} \mathrm{C}\) for \begin{tabular}{l} 
MC34080B \\
MC34081B
\end{tabular} & Thigh \(=+70^{\circ} \mathrm{C}\) for \(\mathrm{MC34080B}\) \\
MC34084 & MC34081B \\
MC34085 & MC34084
\end{tabular}
4. See application information for typical changes in input offset voltage due to solderability and temperature cycling 5. Limits at \(\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}\) are guaranteed by high temperature ( \(\mathrm{T}_{\text {high }}\) ) testing.

\section*{MC34080 thru MC34085}

AC ELECTRICAL CHARACTERISTICS \(\left(\mathrm{V}_{\mathrm{CC}}=+15 \mathrm{~V}, \mathrm{~V}_{\mathrm{EE}}=-15 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}\right.\), unless otherwise noted.)
\begin{tabular}{|c|c|c|c|c|c|}
\hline Characteristics & Symbol & Min & Typ & Max & Unit \\
\hline  & SR & \(\frac{20}{35}\) & 25
30
50
50 & - & V/us \\
\hline \[
\begin{gathered}
\text { Settling Time (10 V Step, AV }=-1.0) \\
\text { To } 0.10 \%( \pm 1 / 2 \text { LSB of } 9-\text { Bits }) \\
\text { To } 0.01 \%( \pm 1 / 2 \text { LSB of } 12-\text { Bits })
\end{gathered}
\] & \(t_{s}\) & 二 & \[
\begin{gathered}
0.72 \\
1.6
\end{gathered}
\] & & \(\mu \mathrm{s}\) \\
\hline Gain Bandwidth Product ( \(\mathrm{f}=200 \mathrm{kHz}\) ) Compensated Decompensated & GBW & \[
\begin{aligned}
& 6.0 \\
& 12
\end{aligned}
\] & \[
\begin{gathered}
8.0 \\
16
\end{gathered}
\] & - & MHz \\
\hline \[
\begin{aligned}
& \text { Power Bandwidth }\left(R_{\mathrm{L}}=2.0 \mathrm{k}, \mathrm{~V}_{\mathrm{O}}=20 \mathrm{~V}_{\mathrm{pp}}, \mathrm{THD}=5.0 \%\right) \\
& \text { Compensated } \mathrm{AV}=+1.0 \\
& \text { Decompensated } \mathrm{AV}_{\mathrm{V}}=-1.0
\end{aligned}
\] & BWp & 二 & \[
\begin{aligned}
& 400 \\
& 800
\end{aligned}
\] & & kHz \\
\hline \[
\begin{aligned}
& \hline \text { Phase Margin (Compensated) } \\
& R_{L}=2.0 \mathrm{k} \\
& R_{L}=2.0 \mathrm{k}, C_{L}=100 \mathrm{pF}
\end{aligned}
\] & ¢m & - & 55
39 & - & Degrees \\
\hline \[
\begin{aligned}
& \text { Gain Margin (Compensated) } \\
& R_{\mathrm{L}}=2.0 \mathrm{k} \\
& \mathrm{R}_{\mathrm{L}}=2.0 \mathrm{k}, \mathrm{C}_{\mathrm{L}}=100 \mathrm{pF}
\end{aligned}
\] & \(A_{m}\) & & \[
\begin{aligned}
& 7.6 \\
& 4.5
\end{aligned}
\] & - & dB \\
\hline Equivalent Input Noise Voltage
\[
\mathrm{R}_{\mathrm{S}}=100 \Omega, \mathrm{f}=1.0 \mathrm{kHz}
\] & \(\mathrm{e}_{\mathrm{n}}\) & - & 30 & - & \(\mathrm{nV} / \sqrt{\mathrm{Hz}}\) \\
\hline Equivalent Input Noise Current ( \(\mathrm{f}=1.0 \mathrm{kHz}\) ) & In & - & 0.01 & - & \(\mathrm{pA} / \sqrt{\mathrm{Hz}}\) \\
\hline Input Capacitance & \(\mathrm{C}_{\mathrm{i}}\) & - & 5.0 & - & pF \\
\hline Input Resistance & \(\mathrm{r}_{\mathrm{i}}\) & - & \(10^{12}\) & - & \(\Omega\) \\
\hline Total Harmonic Distortion
\[
A V=+10, R_{L}=2.0 \mathrm{k}, 2.0 \leq \mathrm{V}_{\mathrm{O}} \leq 20 \mathrm{~V}_{\mathrm{pp}}, \mathrm{f}=10 \mathrm{kHz}
\] & THD & - & 0.05 & - & \% \\
\hline Channel Separation ( \(\mathrm{f}=10 \mathrm{kHz}\) ) & - & - & 120 & - & dB \\
\hline Open Loop Output Impedance ( \(\mathrm{f}=1.0 \mathrm{MHz}\) ) & \(\mathrm{Z}_{0}\) & - & 35 & - & \(\Omega\) \\
\hline
\end{tabular}

Figure 1. Input Common Mode Voltage Range versus Temperature


Figure 2. Input Bias Current versus Temperature


Figure 3. Input Bias Current versus Input Common Mode Voltage


Figure 5. Output Saturation versus Load Current


Figure 7. Output Saturation versus Load Resistance to VCC


Figure 4. Output Voltage Swing versus Supply Voltage


Figure 6. Output Saturation vesus Load Resistance to Ground


Figure 8. Output Short Circuit Current versus Temperature


\section*{MC34080 thru MC34085}

Figure 9. Output Impedance versus Frequency


Figure 10. Output Impedance versus Frequency


Figure 12. Output Distortion versus Frequency


Figure 13. Open Loop Voltage Gain versus Temperature


Figure 14. Open Loop Voltage Gain and Phase versus Frequency


Figure 16. Open Loop Voltage Gain and Phase versus Frequency


Figure 18. Percent Overshoot versus Load Capacitance


Figure 15. Open Loop Voltage Gain and Phase versus Frequency


Figure 17. Normalized Gain Bandwidth Product versus Temperature


Figure 19. Phase Margin versus Load Capacitance


Figure 20. Gain Margin versus Load Capacitance


Figure 22. Gain Margin versus Temperature


Figure 21. Phase Margin versus Temperature


Figure 23. Normalized Slew Rate versus Temperature


\section*{MC34080 thru MC34085}

MC34084 Transient Response
\[
\mathrm{AV}=+1.0, \mathrm{R}_{\mathrm{L}}=2.0 \mathrm{k}, \mathrm{~V}_{\mathrm{CC}} / \mathrm{V}_{\mathrm{EE}}= \pm 15 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}
\]

Figure 24. Small Signal

\(0.2 \mu \mathrm{~s} /\) Div

Figure 25. Large Signal

\(0.5 \mu \mathrm{~s} /\) Div

MC34085 Transient Response
\(\mathrm{AV}=+2.0, \mathrm{R}_{\mathrm{L}}=2.0 \mathrm{k}, \mathrm{V}_{\mathrm{CC}} / \mathrm{V}_{\mathrm{EE}}= \pm 15 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}\)

Figure 26. Small Signal

\(0.2 \mu \mathrm{~s} /\) Div

Figure 27. Large Signal

\(0.5 \mu \mathrm{~s} /\) Div

\section*{MC34080 thru MC34085}

Figure 28. Common Mode Rejection Ratio versus Frequency


Figure 30. Power Supply Rejection Ratio versus Temperature


Figure 32. Channel Separation versus Frequency


Figure 29. Power Supply Rejection Ratio versus Frequency


Figure 31. Normalized Supply Current versus Supply Voltage


Figure 33. Spectral Noise Density


\section*{MC34080 thru MC34085}

\section*{APPLICATIONS INFORMATION}

The bandwidth and slew rate of the MC34080 series is nearly double that of currently available general purpose JFET op-amps. This improvement in AC performance is due to the P-channel JFET differential input stage driving a compensated miller integration amplifier in conjunction with an all NPN output stage.

The all NPN output stage offers unique advantages over the more conventional NPN/PNP transistor Class AB output stage. With a 10 k load resistance, the op amp can typically swing within 1.0 V of the positive rail ( \(\mathrm{V}_{\mathrm{CC}}\) ), and within 0.3 V of the negative rail ( \(\mathrm{V}_{\mathrm{EE}}\) ), providing a \(28.7 \mathrm{p}-\mathrm{p}\) swing from \(\pm 15 \mathrm{~V}\) supplies. This large output swing becomes most noticeable at lower supply voltages. If the load resistance is referenced to \(\mathrm{V}_{\mathrm{CC}}\) instead of ground, the maximum possible output swing can be achieved for a given supply voltage. For light load currents, the load resistance will pull the output to \(\mathrm{V}_{\mathrm{CC}}\) during the positive swing and the NPN output transistor will pull the output very near \(\mathrm{V}_{\mathrm{EE}}\) during the negative swing. The load resistance value should be much less than that of the feedback resistance to maximize pull-up capability.

The all NPN transistor output stage is also inherently fast, contributing to the operation amplifier's high gain-bandwidth product and fast settling time. The associated high frequency output impedance is \(50 \Omega\) (typical) at 8.0 MHz . This allows driving capacitive loads from 0 pF to 300 pF without oscillations over the military temperature range, and over the full range of output swing. The \(55^{\circ} \mathrm{C}\) phase margin and 7.6 dB gain margin as well as the general gain and phase characteristics are virtually independent of the sink/source output swing conditions. The high frequency characteristics of the MC34080 series is especially useful for active filter applications.

The common mode input range is from 2.0 V below the positive rail ( \(\mathrm{V}_{\mathrm{CC}}\) ) to 4.0 V above the negative rail ( \(\mathrm{V}_{\mathrm{EE}}\) ). The amplifier remains active if the inputs are biased at the positive rail. This may be useful for some applications in that single supply operation is possible with a single negative supply. However, a degradation of offset voltage and voltage gain may result.

Phase reversal does not occur if either the inverting or noninverting input (or both) exceeds the positive common mode limit. If either input (or both) exceeds the negative common mode limit, the output will be in the high state. The
input stage also allows a differential up to \(\pm 44 \mathrm{~V}\), provided the maximum input voltage range is not exceeded. The supply voltage operating range is from \(\pm 5.0 \mathrm{~V}\) to \(\pm 22 \mathrm{~V}\).

For optimum frequency performance and stability, careful component placement and printed circuit board layout should be exercised. For example, long unshielded input or output leads may result in unwanted input-output coupling. In order to reduce the input capacitance, resistors connected to the input pins should be physically close to these pins. This not only minimizes the input pole for optimum frequency response, but also minimizes extraneous "pickup" at this node.

Supply decoupling with adequate capacitance close to the supply pin is also important, particularly over temperature, since many types of decoupling capacitors exhibit large impedance changes over temperature.

Primarily due to the JFET inputs of the op amp, the input offset voltage may change due to temperature cycling and board soldering. After 20 temperature cycles ( \(-55^{\circ}\) to \(165^{\circ} \mathrm{C}\) ), the typical standard deviation for input offset voltage is \(559 \mu \mathrm{~V}\) in the plastic packages. With respect to board soldering ( \(260^{\circ} \mathrm{C}, 10\) seconds), the typical standard deviation for input offset voltage is \(525 \mu \mathrm{~V}\) in the plastic package. Socketed devices should be used over a minimal temperature range for optimum input offset voltage performance.

Figure 34. Offset Nulling Circuit


\section*{OUTLINE DIMENSIONS}


\section*{MC34080 thru MC34085}

\section*{OUTLINE DIMENSIONS}


\section*{MC34080 thru MC34085}

\section*{NOTES}

\section*{MC34080 thru MC34085}

\section*{NOTES}

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